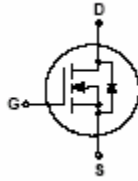
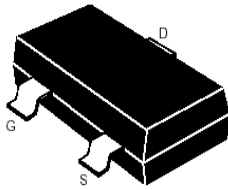


SOT-23

Features

- Low $R_{DS(on)}$ @ $V_{GS}=10V$
- 3.3V Logic Level Control
- N Channel SOT23 Package
- Pb-Free, RoHS Compliant

Applications

- DC-to-DC converters
- Power management in battery-driven portables
- Low-side load switch and charging switch for portable devices
- Switching circuits
- High-speed line driver

$V_{(BR)DSS}$	$R_{DS(ON)}$ Typ	I_D Max
30V	28m Ω @10V	5.1A
	34m Ω @4.5V	

Order Information

Product	Package	Marking	Packing	Min Unit Quantity
BM3402	SOT23	WT3H	3000PCS/Reel	3000PCS

Absolute Maximum Ratings

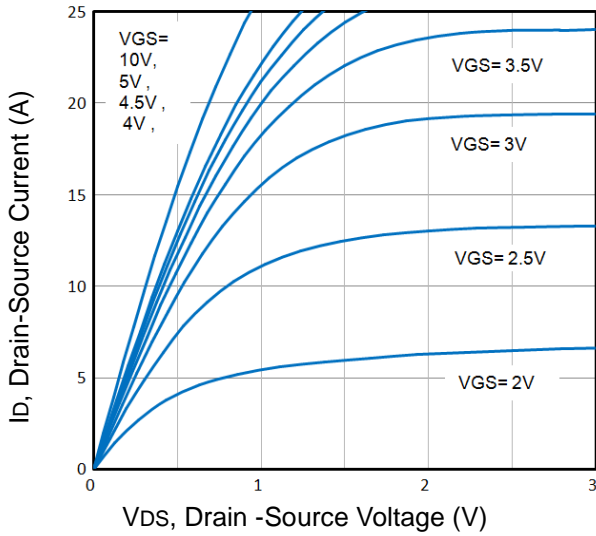
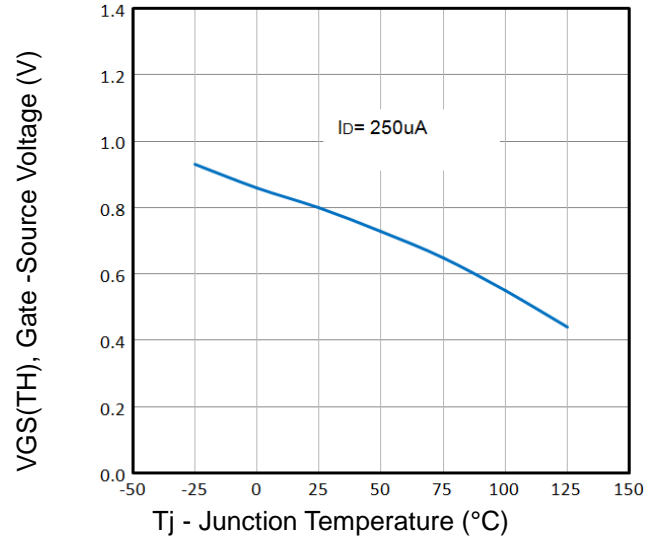
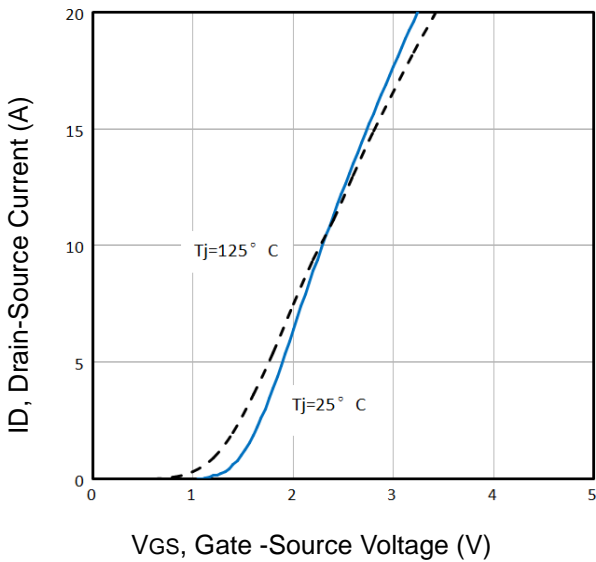
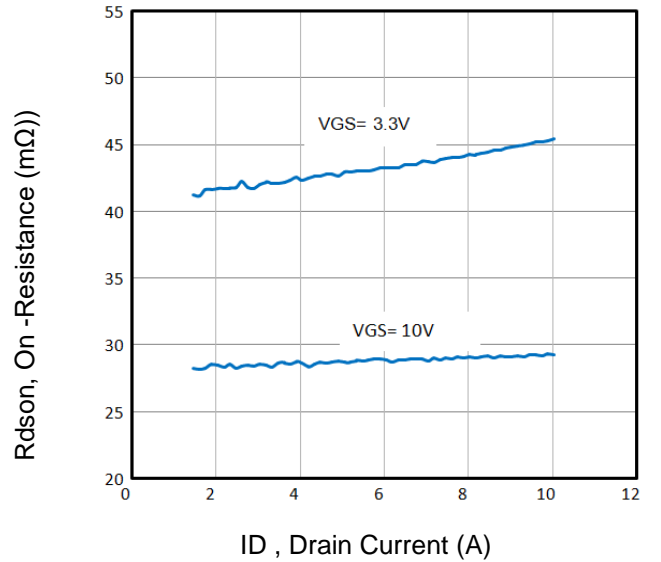
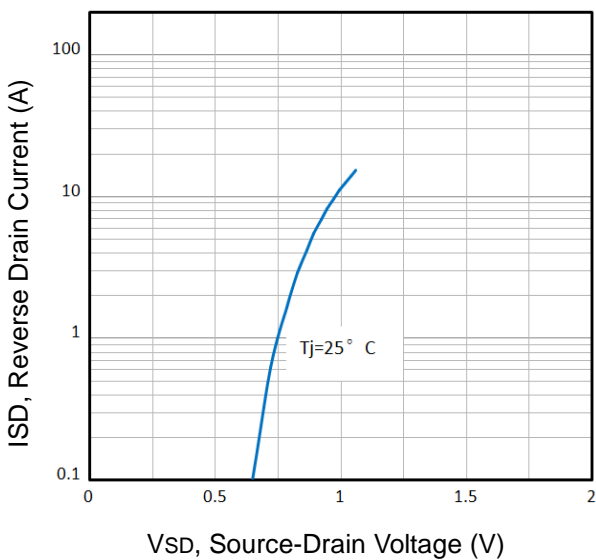
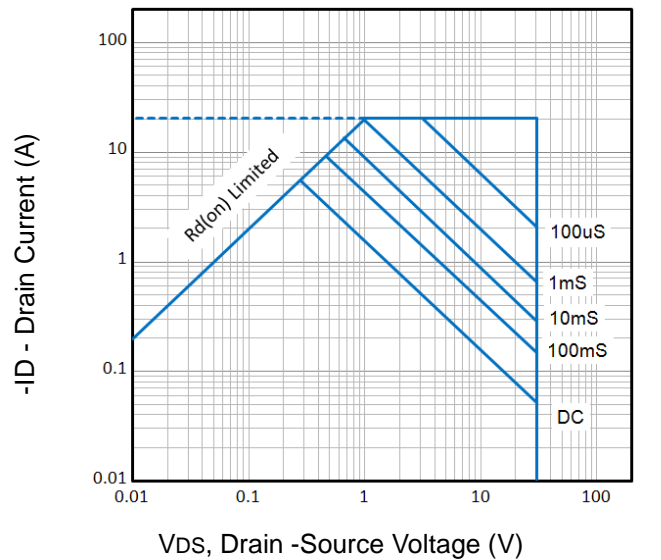
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

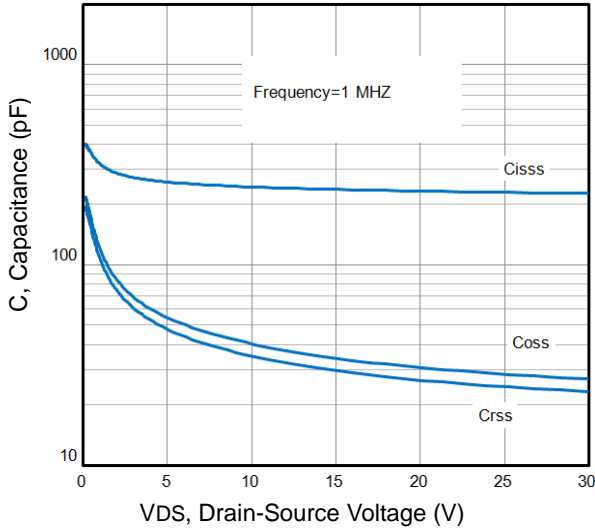
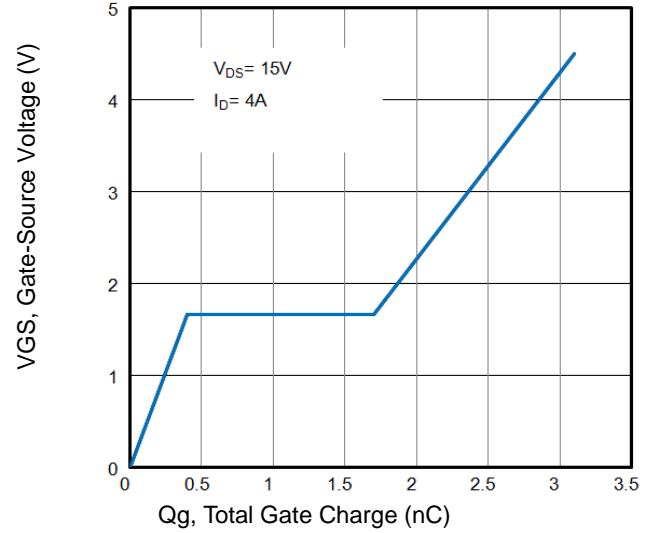
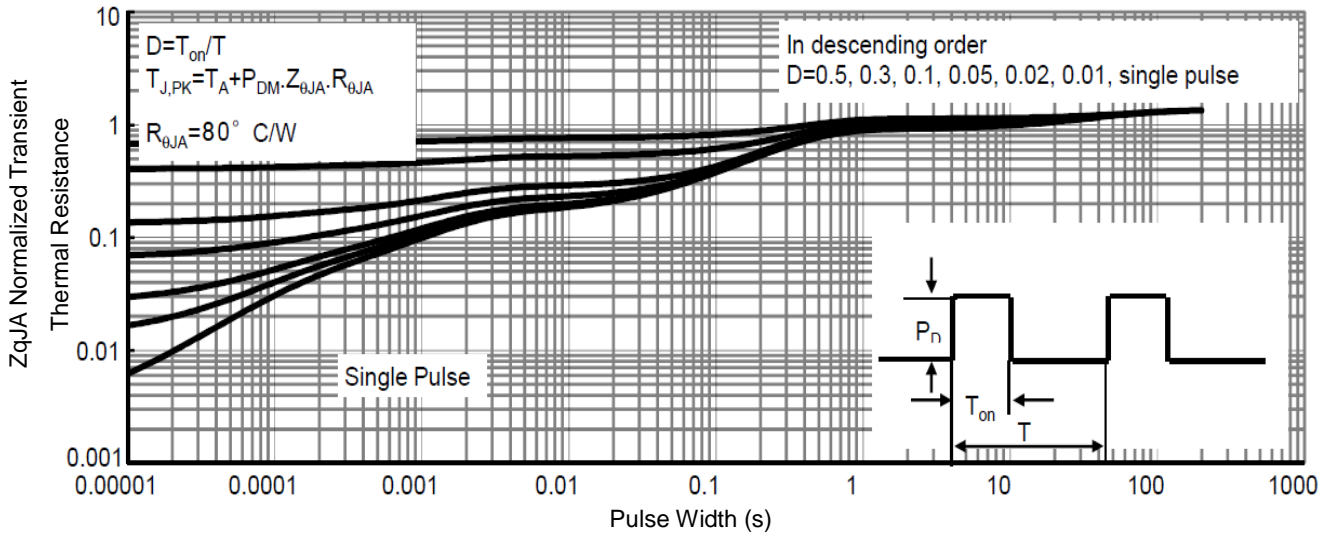
Symbol	Parameter	Rating	Unit
Common Ratings ($T_A=25^\circ\text{C}$ Unless Otherwise Noted)			
V_{GS}	Gate-Source Voltage	± 16	V
$V_{(BR)DSS}$	Drain-Source Breakdown Voltage	30	V
T_J	Maximum Junction Temperature	150	$^\circ\text{C}$
T_{STG}	Storage Temperature Range	-50 to 150	$^\circ\text{C}$
Mounted on Large Heat Sink			
I_{DM}	Pulse Drain Current Tested①	$T_A=25^\circ\text{C}$	20.4 A
I_D	Continuous Drain Current	$T_A=25^\circ\text{C}$	5.1 A
		$T_A=70^\circ\text{C}$	4 A
P_D	Maximum Power Dissipation	$T_A=25^\circ\text{C}$	1.5 W
		$T_A=70^\circ\text{C}$	0.9 W
$R_{\theta JA}$	Thermal Resistance Junction-Ambient	80	$^\circ\text{C/W}$

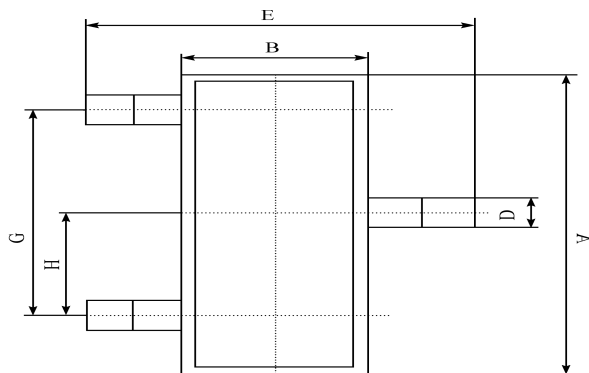


Symbol	Parameter	Condition	Min	Typ	Max	Unit
Static Electrical Characteristics @ T_J = 25°C (unless otherwise stated)						
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V I _D =250μA	30	--	--	V
I _{DSS}	Zero Gate Voltage Drain Current(T _A =25°C)	V _{DS} =30V, V _{GS} =0V	--	--	1	μA
	Zero Gate Voltage Drain Current(T _A =125°C)	V _{DS} =24V, V _{GS} =0V	--	--	100	uA
I _{GSS}	Gate-Body Leakage Current	V _{GS} =±16V, V _{DS} =0V	--	--	±100	nA
V _{GS(TH)}	Gate Threshold Voltage	V _{DS} =V _{GS} , I _D =250μA	0.5	0.8	1.2	V
R _{DS(ON)}	Drain-Source On-State Resistance ^②	V _{GS} =10V, I _D =4A	--	28	36	mΩ
R _{DS(ON)}	Drain-Source On-State Resistance ^②	V _{GS} =4.5V, I _D =3A	--	34	50	mΩ
R _{DS(ON)}	Drain-Source On-State Resistance ^②	V _{GS} =3.3V, I _D =2A	--	40	60	mΩ
R _{DS(ON)}	Drain-Source On-State Resistance ^②	V _{GS} =2.5V, I _D =1A	--	55	80	mΩ
Dynamic Electrical Characteristics @ T_J = 25°C (unless otherwise stated)						
C _{iss}	Input Capacitance	V _{DS} =15V, V _{GS} =0V, f=1MHz	--	240	--	pF
C _{oss}	Output Capacitance		--	35	--	pF
C _{rss}	Reverse Transfer Capacitance		--	30	--	pF
Q _g	Total Gate Charge	V _{DS} =15V I _D =4A, V _{GS} =4.5V	--	3.1	--	nC
Q _{gs}	Gate Source Charge		--	0.4	--	nC
Q _{gd}	Gate Drain Charge		--	1.3	--	nC
Switching Characteristics						
t _{d(on)}	Turn on Delay Time	V _{DD} =15V, I _D =1A, R _G =3.3Ω, V _{GS} =10V	--	4.4	--	ns
t _r	Turn on Rise Time		--	2.6	--	ns
t _{d(off)}	Turn Off Delay Time		-	25.5	--	ns
t _f	Turn Off Fall Time		--	3.3	--	ns
Source Drain Diode Characteristics						
I _{SD}	Source drain current(Body Diode)	T _A =25°C	--	--	1.8	A
V _{SD}	Forward on voltage ^②	T _J =25°C, I _{SD} =4A, V _{GS} =0V	--	0.85	1.2	V

Notes: ① Pulse width limited by maximum allowable junction temperature

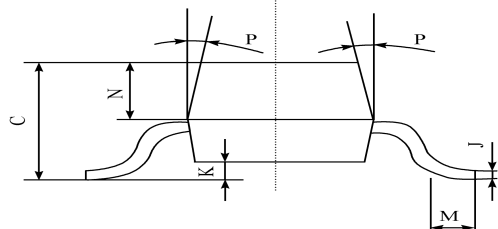

Typical Characteristics

Fig1. Typical Output Characteristics

Fig2. Normalized Threshold Voltage Vs. Temperature

Fig3. Typical Transfer Characteristics

Fig4. On-Resistance vs. Drain Current and Gate

Fig5. Typical Source-Drain Diode Forward Voltage

Fig6. Maximum Safe Operating Area

Typical Characteristics

Fig7. Typical Capacitance Vs. Drain-Source Voltage

Fig8. Typical Gate Charge Vs. Gate-Source Voltage

Fig9. Normalized Maximum Transient Thermal Impedance

SOT-23 PACKAGE OUTLINE Plastic surface mounted package


SOT-23	
A	2.90 ± 0.10
B	1.30 ± 0.10
C	1.00 ± 0.10
D	0.40 ± 0.10
E	2.40 ± 0.20
G	1.90 ± 0.10
H	0.95 ± 0.05
J	0.13 ± 0.05
K	0.00-0.10
M	≥ 0.2
N	0.60 ± 0.10
P	7 ± 2°

(UNIT): mm



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